

### Vishay Semiconductors

# White LED in 3mm T 1 Waterclear Package



#### **DESCRIPTION**

High Intensity LED with typical color coordinates x = 0.33, y = 0.33 (typical color temperature 5500 k). This LED emits white light with a high color rendering index.

The emission spectrum is tuned for ideal white, without the impression of being blue shaded or "cold". The package is a standard 3 mm.

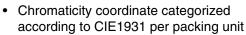
The internal reflector is filled with a compound of TAG phosphor and an elastic resin.

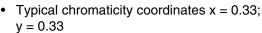
Therefore the chip is better protected against temperature cycle stress.

The phosphor converts the blue emission of the InGaN chip partially to amber, which mixes with the remaining blue to produce white.

#### **FEATURES**

· High efficient InGaN technology







- ESD-withstand voltage up to 1 kV acc. to JESD22-A114-B
- · Small viewing angle, high luminous intensity
- Chip embedded in elastic resin, improved robustness against temperature cycle stress
- Lead (Pb)-free device
- · RoHS compliant

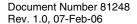
#### **APPLICATIONS**

- · Indicator and backlighting
- Indoor and outdoor message panels
- · Alternative to incandescent lamps
- Marker lights

PARTS TABLE			
PART	COLOR, LUMINOUS INTENSITY	ANGLE OF HALF INTENSITY (± J)	TECHNOLOGY
VLHW4900	White, I <sub>V</sub> > 240 mcd	16°	InGaN / TAG on SiC
VLHW4902	White, $I_V = (430 \text{ to } 2000) \text{ mcd}$	16°	InGaN / TAG on SiC







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ABSOLUTE MAXIMUM RATINGS <sup>1)</sup> VLHW490.				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage <sup>2)</sup>		V <sub>R</sub>	5	V
DC Forward current	T <sub>amb</sub> ≤ 50 °C	I <sub>F</sub>	30	mA
Surge forward current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	0.1	А
Power dissipation		P <sub>V</sub>	126	mW
Junction temperature		T <sub>j</sub>	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s	T <sub>sd</sub>	260	°C
Thermal resistance junction/ ambient		R <sub>thJA</sub>	400	K/W

 $<sup>^{1)}</sup>$  T<sub>amb</sub> = 25  $^{\circ}$ C, unless otherwise specified

<sup>&</sup>lt;sup>2)</sup> Driving the LED in reverse direction is suitable for short term application

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	I <sub>F</sub> = 20 mA	VLHW4900	I <sub>V</sub>	240	500		mcd
		VLHW4902	I <sub>V</sub>	430		2000	mcd
Luminous flux	I <sub>F</sub> = 20 mA		φV		250		mlm
Chromaticity coordinate x acc. to CIE 1931	I <sub>F</sub> = 20 mA		х		0.33		
Chromaticity coordinate y acc. to CIE 1931	I <sub>F</sub> = 20 mA		у		0.33		
Angle of half intensity	I <sub>F</sub> = 20 mA		φ		± 16		deg
Forward voltage	I <sub>F</sub> = 20 mA		$V_{F}$		3.5	4.2	V
Reverse voltage	I <sub>R</sub> = 10 μA		$V_{R}$	5			V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 20 mA		TC <sub>V</sub>		- 4		mV/K
Temperature coefficient of I <sub>V</sub>	I <sub>F</sub> = 20 mA		TCI		- 0.5		% / K

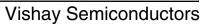
 $<sup>^{1)}</sup>$  T<sub>amb</sub> = 25 °C, unless otherwise specified

 $<sup>^{2)}</sup>$  in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$ 

CHROMATICITY COORDINATE CLASSIFICATION				
GROUP	X		Y	
	MIN	MAX	MIN	MAX
3	0.280	0.325	0.210	0.340
4	0.305	0.350	0.260	0.390
5	0.330	0.375	0.310	0.440

LUMINOUS INTENSITY CLASSIFICATION				
GROUP	LIGHT INTENSITY [MCD]			
STANDARD	MIN	MAX		
Z	240	480		
AA	320	640		
BB	430	860		
CC	575	1150		
DD	750	1500		
EE	1000	2000		

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### TYPICAL CHARACTERISTICS (TAMB = 25 °C UNLESS OTHERWISE SPECIFIED)

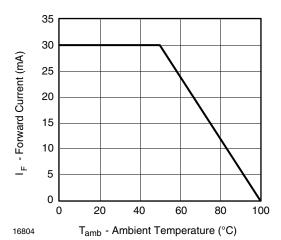


Figure 1. Forward Current vs. Ambient Temperature

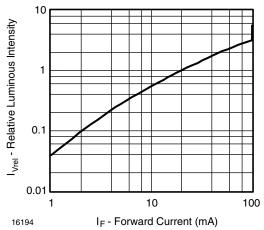


Figure 2. Relative Luminous Intensity vs. Forward Current

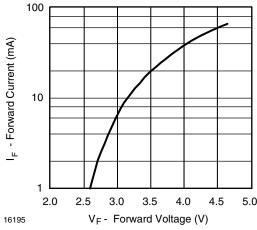


Figure 3. Forward Current vs. Forward Voltage

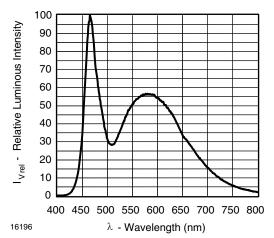


Figure 4. Relative Intensity vs. Wavelength

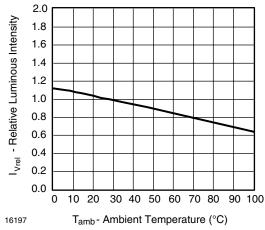


Figure 5. Rel. Luminous Intensity vs. Ambient Temperature

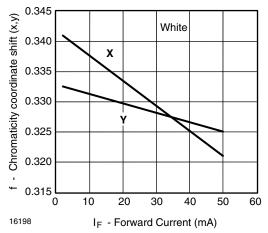


Figure 6. Chromaticity Coordinate Shift vs. Forward Current

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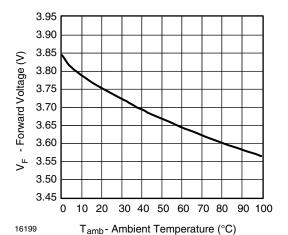


Figure 7. Forward Voltage vs. Ambient Temperature

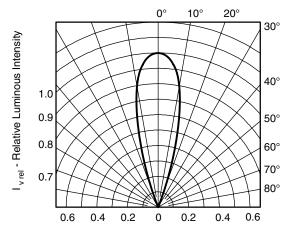


Figure 8. Rel. Luminous Intensity vs. Angular Displacement

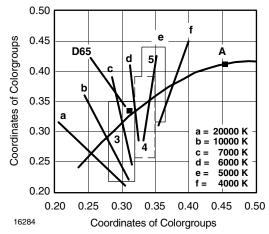


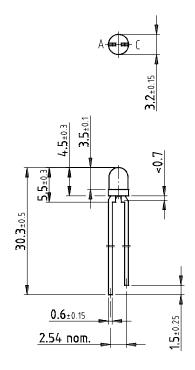
Figure 9. Coordinates of Colorgroups

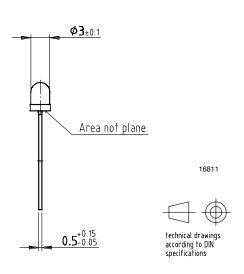
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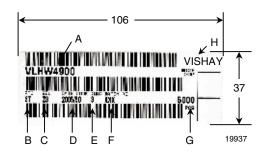
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### **PACKAGE DIMENSIONS IN MM**





### **BARCODE-PRODUCT-LABEL**



- A) Type of component
- B) Manufacturing plant
- C) SEL Selection Code (Bin):
  - e.g.: Z = Code for Luminous Intensity Group 3 = Code for Chromaticity Coordinate
- D) Date Code year/week
- E) Day Code (e.g. 1: Monday)
- F) Batch No.
- G) Total quantity
- H) Company Code

### **VLHW490.**

### Vishay Semiconductor



### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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### **Legal Disclaimer Notice**



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